

NAND01GR3B2BZA6E

NAND01GR3B2BZA6E Information

	NAND01GR3B2BZA6E Micron Technology Inc. Integrated Circuits (ICs) Memory IC FLASH 1GBIT 30NS 63VFBGA 63-TFBGA For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NAND01GR3B2BZA6E Specifications

Manufacturer Part Number	NAND01GR3B2BZA6E
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	63-TFBGA
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	1Gb (128M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	30ns
Access Time	30ns
Voltage - Supply	1.7 V ~ 1.95 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	63-TFBGA
Supplier Device Package	63-VFBGA (9x11)
	Report errors?

NAND01GR3B2BZA6E Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NAND01GR3B2BZA6E Payment Methods





If you have any question about NAND01GR3B2BZA6E, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com